1.0 A Output Current, Dual Power Operational Amplifiers

The TCA0372 is a monolithic circuit intended for use as a power operational amplifier in a wide range of applications, including servo amplifiers and power supplies. No deadband crossover distortion provides better performance for driving coils.

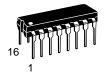
- Output Current to 1.0 A
- Slew Rate of 1.3 V/µs
- Wide Bandwidth of 1.1 MHz
- Internal Thermal Shutdown
- Single or Split Supply Operation
- Excellent Gain and Phase Margins
- Common Mode Input Includes Ground
- Zero Deadband Crossover Distortion



http://onsemi.com



PDIP-8 DP1 SUFFIX CASE 626



PDIP-16 DP2 SUFFIX CASE 648



SO-16W DW SUFFIX CASE 751G



SOEIAJ-16 DM2 SUFFIX CASE 966

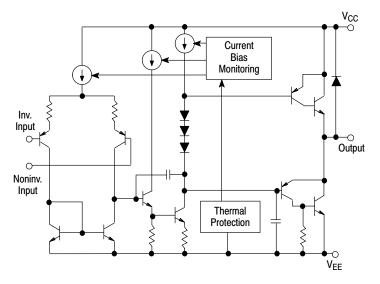


Figure 1. Representative Block Diagram

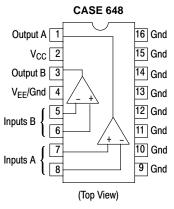
ORDERING INFORMATION

| Device | Package | Shipping |
|--------------|-----------|------------------|
| TCA0372DW | SO-16W | 47 Units/Rail |
| TCA0372DWR2 | SO-16W | 1000 Tape & Reel |
| TCA0372DP1 | PDIP-8 | 50 Units/Rail |
| TCA0372BDP1 | PDIP-8 | 50 Units/Rail |
| TCA0372DP2 | PDIP-16 | 25 Units/Rail |
| TCA0372DM2EL | SOEIAJ-16 | 2500 Tape & Reel |

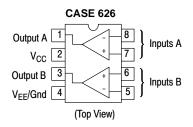
DEVICE MARKING INFORMATION

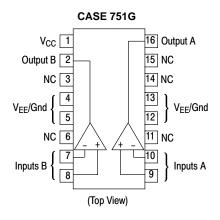
See general marking information in the device marking section on page 6 of this data sheet.

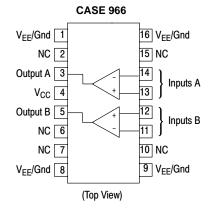
PIN CONNECTIONS



*Pins 4 and 9 to 16 are internally connected.







MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|--------------------|-----------------|------|
| Supply Voltage (from V _{CC} to V _{EE}) | V _S | 40 | V |
| Input Differential Voltage Range | V_{IDR} | Note 1 | V |
| Input Voltage Range | V _{IR} | Note 1 | V |
| Junction Temperature (Note 2) | T _J | +150 | °C |
| Operating Temperature Range | T _A | -40 to +125 | °C |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |
| DC Output Current | lo | 1.0 | А |
| Peak Output Current (Nonrepetitive) | I _(max) | 1.5 | А |
| Thermal Resistance, Junction–to–Air Case 626 Case 648 Case 751G | R _{θJA} | 137 72 80 | °C/W |
| Thermal Resistance, Junction–to–Case Case 626 Case 648 Case 751G | $R_{	heta JC}$ | 23 10 12 | °C/W |

- Either or both input voltages should not exceed the magnitude of V_{CC} or V_{EE}.
 Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded.

DC ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, R_L connected to ground, T_A = -40° to +125°C.)

| Characteristics | Symbol | Min | Тур | Max | Unit |
|--|--------------------------|--|-------------------------|----------------------|-------|
| Input Offset Voltage ($V_{CM} = 0$) $T_A = +25^{\circ}C$ $T_A, T_{low} \text{ to } T_{high}$ | V _{IO} | _ _ | 1.0 _ | 15 20 | mV |
| Average Temperature Coefficient of Offset Voltage | $\Delta V_{IO}/\Delta T$ | _ | 20 | _ | μV/°C |
| Input Bias Current (V _{CM} = 0) | I _{IB} | _ | 100 | 500 | nA |
| Input Offset Current (V _{CM} = 0) | I _{IO} | _ | 10 | 50 | nA |
| Large Signal Voltage Gain $V_0 = \pm 10 \text{ V, } R_L = 2.0 \text{ k}$ | A _{VOL} | 30 | 100 | _ | V/mV |
| Output Voltage Swing (I_L = 100 mA) $T_A = +25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$ $T_A = +25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$ | V _{OH} | 14.0 13.9 – | 14.2 - -14.2 - | - -14.0 -13.9 | V |
| Output Voltage Swing ($I_L = 1.0 \text{ A}$) $V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = +25^{\circ}\text{C}$ $V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = T_{low} \text{ to } T_{high}$ $V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = +25^{\circ}\text{C}$ $V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = T_{low} \text{ to } T_{high}$ | V _{OH} | 22.5 22.5 – | 22.7 - 1.3 - | - - 1.5 1.5 | V |
| Input Common Mode Voltage Range $T_A = +25$ °C $T_A = T_{low}$ to T_{high} | V _{ICR} | V _{EE} to (V _{CC} -1.0) V _{EE} to (V _{CC} -1.3) | | V | |
| Common Mode Rejection Ratio (R _S = 10 k) | CMRR | 70 | 90 | _ | dB |
| Power Supply Rejection Ratio ($R_S = 100 \Omega$) | PSRR | 70 | 90 | _ | dB |
| $\begin{aligned} & \text{Power Supply Current} \\ & T_{A} = +25^{\circ}\text{C} & \text{TCA0372} \\ & & \text{TCA0372B} \\ & T_{A} = T_{low} \text{ to } T_{high} & \text{TCA0372} \\ & & \text{TCA0372B} \end{aligned}$ | I _D | - - - | 5.0 8.0 - - | 10 10 14 14 | mA |

$\textbf{AC ELECTRICAL CHARACTERISTICS} \ (V_{CC} = +15 \ V, \ V_{EE} = -15 \ V, \ R_L \ connected \ to \ ground, \ T_A = +25 ^{\circ}C, \ unless \ otherwise \ noted.)$

| Characteristics | Symbol | Min | Тур | Max | Unit |
|---|----------------|------------|----------|-----|---------|
| Slew Rate ($V_{in} = -10 \text{ V to } +10 \text{ V}$, $R_L = 2.0 \text{ k}$, $C_L = 100 \text{ pF}$) $A_V = -1.0$, $T_A = T_{low}$ to T_{high} | SR | 1.0 | 1.4 | _ | V/μs |
| Gain Bandwidth Product (f = 100 kHz, C_L = 100 pF, R_L = 2.0 k) T_A = 25°C T_A = T_{low} to T_{high} | GBW | 0.9 0.7 | 1.4 – | 1 1 | MHz |
| Phase Margin $T_J = T_{low}$ to T_{high} $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$ | Фт | _ | 65 | _ | Degrees |
| Gain Margin $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$ | A _m | _ | 15 | _ | dB |
| Equivalent Input Noise Voltage $R_S = 100 \Omega$, $f = 1.0 to 100 kHz$ | e _n | _ | 22 | _ | nV/√Hz |
| Total Harmonic Distortion $A_V = -1.0$, $R_L = 50 \Omega$, $V_O = 0.5 VRMS$, $f = 1.0 kHz$ | THD | - | 0.02 | - | % |

NOTE: In case V_{EE} is disconnected before V_{CC} , a diode between V_{EE} and Ground is recommended to avoid damaging the device.

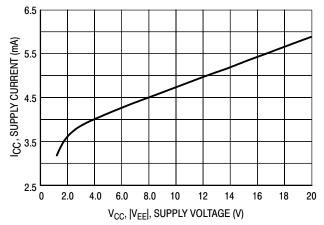


Figure 2. Supply Current versus Supply Voltage with No Load

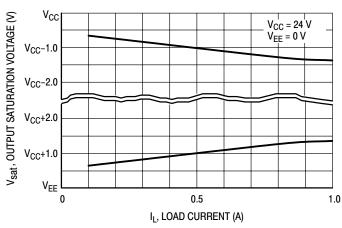


Figure 3. Output Saturation Voltage versus Load Current

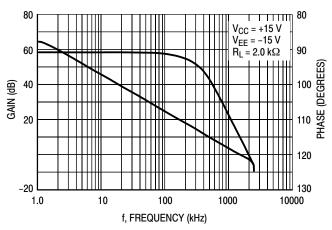


Figure 4. Voltage Gain and Phase versus Frequency

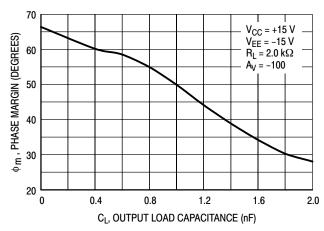


Figure 5. Phase Margin versus Output Load Capacitance

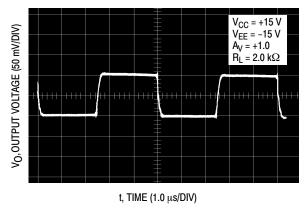


Figure 6. Small Signal Transient Response

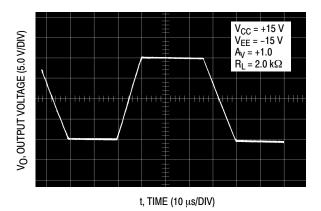


Figure 7. Large Signal Transient Response

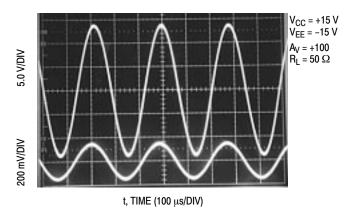


Figure 8. Sine Wave Response

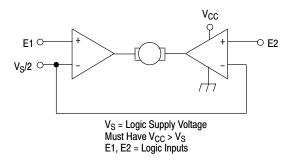
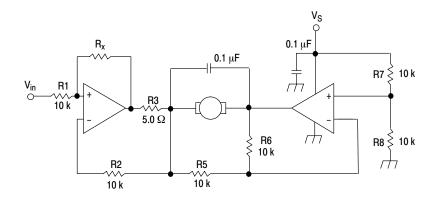


Figure 9. Bidirectional DC Motor Control with Microprocessor–Compatible Inputs



For circuit stability, ensure that $R_X > \frac{2R3 + R1}{R_M}$ where, R_M = internal resistance of motor. The voltage available at the terminals of the motor is: $V_M = 2 (V_1 - \frac{V_S}{2}) + |R_0| \cdot I_M$ where, $|R_0| = \frac{2R3 \cdot R1}{R_X}$ and I_M is the motor current.

Figure 10. Bidirectional Speed Control of DC Motors

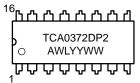
MARKING DIAGRAMS



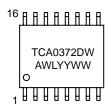




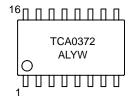
PDIP-16 DP2 SUFFIX CASE 648



SO-16W DW SUFFIX CASE 751G



SOEIAJ-16 DM2 SUFFIX CASE 966

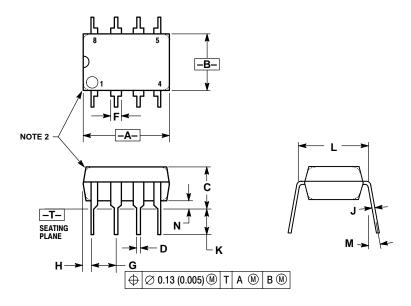


A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

PACKAGE DIMENSIONS

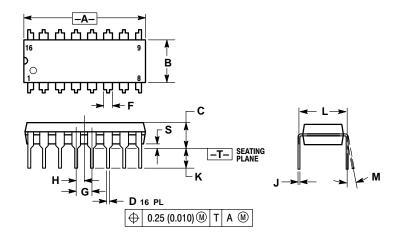
PDIP-8 **DP1 SUFFIX** CASE 626-05 **ISSUE L**



- NOTES:
 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

| | MILLIMETERS | | INC | HES |
|-----|-------------|-------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 9.40 | 10.16 | 0.370 | 0.400 |
| В | 6.10 | 6.60 | 0.240 | 0.260 |
| c | 3.94 | 4.45 | 0.155 | 0.175 |
| D | 0.38 | 0.51 | 0.015 | 0.020 |
| F | 1.02 | 1.78 | 0.040 | 0.070 |
| G | 2.54 BSC | | 0.100 BSC | |
| Н | 0.76 | 1.27 | 0.030 | 0.050 |
| J | 0.20 | 0.30 | 0.008 | 0.012 |
| K | 2.92 | 3.43 | 0.115 | 0.135 |
| L | 7.62 BSC | | 0.300 BSC | |
| M | | 10° | | 10° |
| N | 0.76 | 1.01 | 0.030 | 0.040 |

PDIP-16 **DP2 SUFFIX** CASE 648-08 ISSUE R

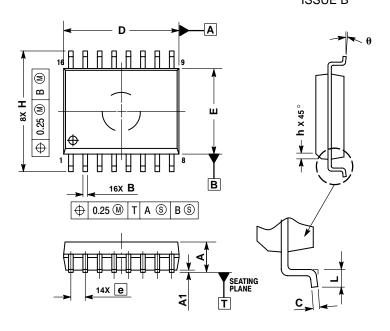


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS WHEN
 FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

| | INCHES | | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.740 | 0.770 | 18.80 | 19.55 |
| В | 0.250 | 0.270 | 6.35 | 6.85 |
| С | 0.145 | 0.175 | 3.69 | 4.44 |
| D | 0.015 | 0.021 | 0.39 | 0.53 |
| F | 0.040 | 0.70 | 1.02 | 1.77 |
| G | 0.100 | BSC | 2.54 | BSC |
| Н | 0.050 | BSC | 1.27 | BSC |
| J | 0.008 | 0.015 | 0.21 | 0.38 |
| K | 0.110 | 0.130 | 2.80 | 3.30 |
| L | 0.295 | 0.305 | 7.50 | 7.74 |
| M | 0° | 10° | 0° | 10 ° |
| S | 0.020 | 0.040 | 0.51 | 1.01 |

PACKAGE DIMENSIONS

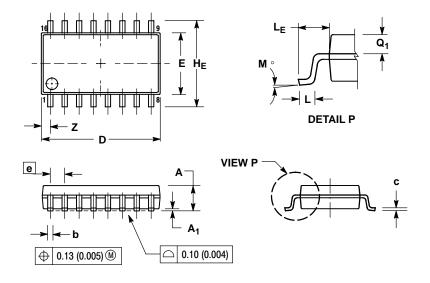
SO-16W **DW SUFFIX** CASE 751G-03 **ISSUE B**



- NOTES:
 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES
 PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INLCUDE MOLD
- PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIMETERS | | |
|-----|-------------|-------|--|
| DIM | MIN | MAX | |
| Α | 2.35 | 2.65 | |
| A1 | 0.10 | 0.25 | |
| В | 0.35 | 0.49 | |
| С | 0.23 | 0.32 | |
| D | 10.15 | 10.45 | |
| Е | 7.40 | 7.60 | |
| е | 1.27 | BSC | |
| Н | 10.05 | 10.55 | |
| h | 0.25 | 0.75 | |
| L | 0.50 | 0.90 | |
| θ | 0 ° | 7 ° | |

SOEIAJ-16 **DM2 SUFFIX** CASE 966-01 **ISSUE O**



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) DED SIDE. PER SIDE.

 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 5. THE LEAD WIDTH DIMENSION (b) DOES NOT
- INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH
 DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| | MILLIMETERS | | INC | HES |
|----------------|-------------|-------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | - | 2.05 | | 0.081 |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| C | 0.18 | 0.27 | 0.007 | 0.011 |
| D | 9.90 | 10.50 | 0.390 | 0.413 |
| Е | 5.10 | 5.45 | 0.201 | 0.215 |
| е | 1.27 | BSC | 0.050 BSC | |
| HE | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| LE | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0 ° | 10 ° | 0 ° | 10° |
| Q ₁ | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | | 0.78 | | 0.031 |

Notes

Notes



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